NSN 5961-01-062-5087

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-062-5087 **Inclosure Material:** Plastic **Overall Length:** 0.800 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.200 inches **Overall Width:** 0.780 inches **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, collector to emitter, sustained all transistor **Current Rating Per Characteristic:** 10.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector absolute all semiconductor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Test Data Document:** 0d0d0-c574000235 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

Demilitarization: Yes - demil/mli

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